

Features

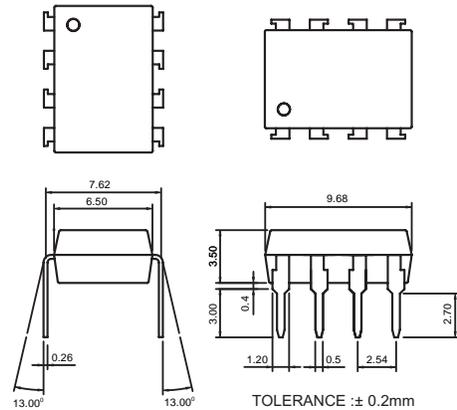
1. High current transfer ratio. (V_{CE0} : 300V MIN.)
(CTR: MIN. 600% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
2. High isolation voltage between input and output.
(Viso: 5000V_{RMS}).
3. Compact dual-in-line package.
4. Available package types: DIP(Shown)/ SMD/ H (Page 148).

Part Numbering System: Page 2. **Part Marking System:** Page 3.

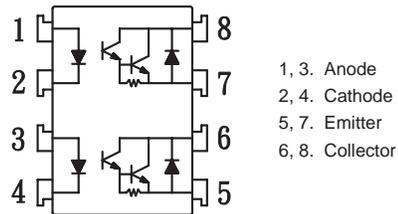
Applications

1. System appliances, measuring instruments.
2. Industrial robots.
3. Copiers, automatic vending machines.
4. Signal transmission between circuits of different potentials and impedances.
5. Telephone sets.
6. Copiers, facsimiles.
7. Interface with various power supply circuits, power distribution boards.
8. Numerical control machines.

Outside Dimension: Unit (mm)



Schematic: Top View



- 1, 3. Anode
2, 4. Cathode
5, 7. Emitter
6, 8. Collector

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P_D	70	mW
Output	Collector-emitter voltage	V_{CE0}	300	V
	Emitter-collector voltage	V_{ECO}	0.1	V
	Collector current	I_C	150	mA
	Collector power dissipation	P_C	200	mW
	Total power dissipation	P_{tot}	200	mW
	Isolation voltage 1 minute	Viso	5000	V _{rms}
	Operating temperature	T_{opr}	-30 to +100	$^\circ\text{C}$
	Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$
	Soldering temperature 10 second	T_{sol}	260	$^\circ\text{C}$

Electro-optical Characteristics

($T_a = 25^\circ\text{C}$)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F = 20\text{mA}$	—	1.2	1.4	V
	Peak forward voltage	V_{FM}	$I_{FM} = 0.5\text{A}$	—	—	3.5	V
	Reverse current	I_R	$V_R = 4\text{V}$	—	—	10	μA
	Terminal capacitance	C_t	$V = 0, f = 1\text{kHz}$	—	30	—	pF
Output	Collector dark current	I_{CEO}	$V_{CE} = 200\text{V}, I_F = 0$	—	—	1	μA
Transfer characteristics	Current transfer ratio	CTR	$I_F = 1\text{mA}, V_{CE} = 2\text{V}$	600	—	9000	%
	Collector-emitter saturation voltage	$V_{CE}(\text{sat})$	$I_F = 20\text{mA}, I_C = 5\text{mA}$	—	—	1.5	V
	Isolation resistance	Riso	DC500V	5×10^{10}	—	—	ohm
	Floating capacitance	C_f	$V = 0, f = 1\text{MHz}$	—	0.6	1.0	pF
	Cut-off frequency	f_c	$V_{CC} = 5\text{V}, I_C = 2\text{mA}, R_L = 100\text{ohm}$	—	7	—	kHz
	Response time (Rise)	t_r	$V_{CE} = 2\text{V}, I_C = 20\text{mA}, R_L = 100\text{ohm}$	—	60	300	μs
Response time (Fall)	t_f	—		50	250	μs	

Fig.1 Current Transfer Ratio vs. Forward Current

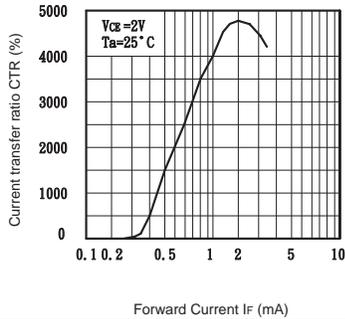


Fig.2 Collector Power Dissipation vs. Ambient Temperature

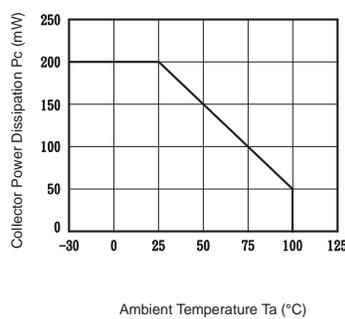


Fig.3 Collector Dark Current vs. Ambient Temperature

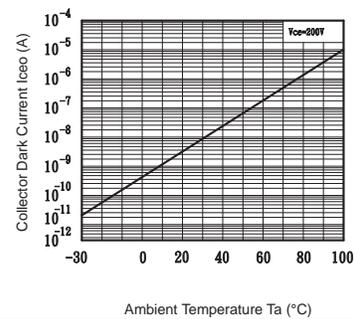


Fig.4 Forward Current vs. Ambient Temperature

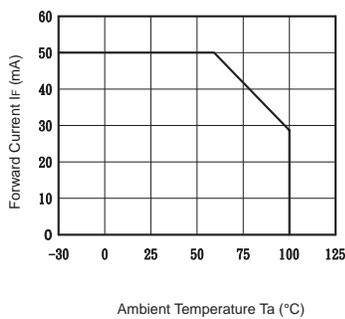


Fig.5 Forward Current vs. Forward Voltage

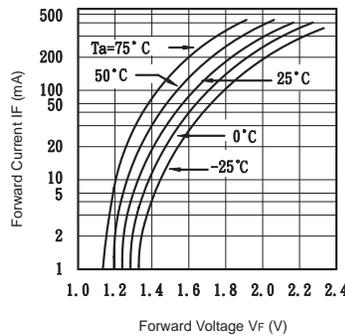


Fig.6 Collector Current vs. Collector-emitter Voltage

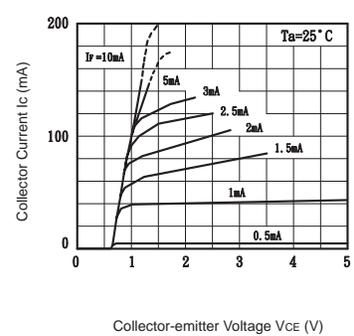


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

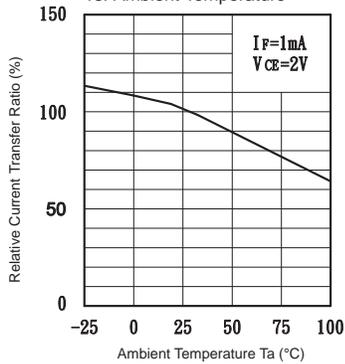


Fig.8 Collector-emitter Saturation Voltage vs. Forward Current

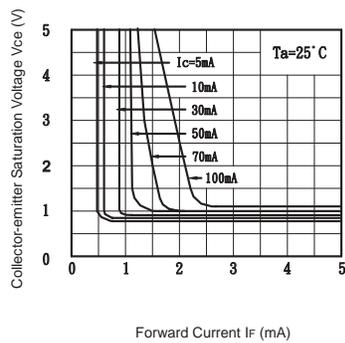
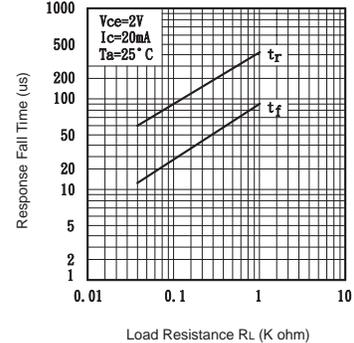


Fig.9 Response Time vs. Load Resistance



Classification table of current transfer ratio

RANK MARK	CTR(%)
E	600 TO 9000